



Wärmewiderstand, Gehäuse bis Kühlkörper Thermal resistance, case to heatsink	pro IGBT / per IGBT $\lambda_{\text{Paste}} = 1 \text{ W/(m}\cdot\text{K)}$ / $\lambda_{\text{grease}} = 1 \text{ W/(m}\cdot\text{K)}$	R_{thCH}		0,064		K/W
Temperatur im Schaltbetrieb Temperature under switching conditions		$T_{\text{vj op}}$	-40		150	°C

Diode, Brems-Chopper / Diode, Brake-Chopper
Höchstzulässige Werte / Maximum Rated Values

Periodische Spitzensperrspannung Repetitive peak reverse voltage	$T_{\text{vj}} = 25^\circ\text{C}$	V_{RRM}		650		V
Dauergleichstrom Continuous DC forward current		I_{F}		400		A
Periodischer Spitzenstrom Repetitive peak forward current	$t_{\text{p}} = 1 \text{ ms}$	I_{FRM}		800		A
Grenzlastintegral I^2t - value	$V_{\text{R}} = 0 \text{ V}, t_{\text{p}} = 10 \text{ ms}, T_{\text{vj}} = 125^\circ\text{C}$ $V_{\text{R}} = 0 \text{ V}, t_{\text{p}} = 10 \text{ ms}, T_{\text{vj}} = 150^\circ\text{C}$	I^2t		8600 7600		A^2s A^2s

Charakteristische Werte / Characteristic Values

				min.	typ.	max.	
Durchlassspannung Forward voltage	$I_{\text{F}} = 400 \text{ A}, V_{\text{GE}} = 0 \text{ V}$ $I_{\text{F}} = 400 \text{ A}, V_{\text{GE}} = 0 \text{ V}$ $I_{\text{F}} = 400 \text{ A}, V_{\text{GE}} = 0 \text{ V}$	$T_{\text{vj}} = 25^\circ\text{C}$ $T_{\text{vj}} = 125^\circ\text{C}$ $T_{\text{vj}} = 150^\circ\text{C}$	V_{F}		1,55 1,50 1,45	1,95	V V V
Rückstromspitze Peak reverse recovery current	$I_{\text{F}} = 400 \text{ A}, -di_{\text{F}}/dt = 4200 \text{ A}/\mu\text{s} (T_{\text{vj}}=150^\circ\text{C})$ $V_{\text{R}} = 300 \text{ V}$	$T_{\text{vj}} = 25^\circ\text{C}$ $T_{\text{vj}} = 125^\circ\text{C}$ $T_{\text{vj}} = 150^\circ\text{C}$	I_{RM}		130 205 215		A A A
Sperrverzögerungsladung Recovered charge	$I_{\text{F}} = 400 \text{ A}, -di_{\text{F}}/dt = 4200 \text{ A}/\mu\text{s} (T_{\text{vj}}=150^\circ\text{C})$ $V_{\text{R}} = 300 \text{ V}$	$T_{\text{vj}} = 25^\circ\text{C}$ $T_{\text{vj}} = 125^\circ\text{C}$ $T_{\text{vj}} = 150^\circ\text{C}$	Q_{r}		10,0 26,5 27,5		μC μC μC
Abschaltenergie pro Puls Reverse recovery energy	$I_{\text{F}} = 400 \text{ A}, -di_{\text{F}}/dt = 4200 \text{ A}/\mu\text{s} (T_{\text{vj}}=150^\circ\text{C})$ $V_{\text{R}} = 300 \text{ V}$	$T_{\text{vj}} = 25^\circ\text{C}$ $T_{\text{vj}} = 125^\circ\text{C}$ $T_{\text{vj}} = 150^\circ\text{C}$	E_{rec}		3,10 6,30 7,40		mJ mJ mJ
Wärmewiderstand, Chip bis Gehäuse Thermal resistance, junction to case	pro Diode / per diode		R_{thJC}			0,21	K/W
Wärmewiderstand, Gehäuse bis Kühlkörper Thermal resistance, case to heatsink	pro Diode / per diode $\lambda_{\text{Paste}} = 1 \text{ W/(m}\cdot\text{K)}$ / $\lambda_{\text{grease}} = 1 \text{ W/(m}\cdot\text{K)}$		R_{thCH}		0,075		K/W
Temperatur im Schaltbetrieb Temperature under switching conditions			$T_{\text{vj op}}$	-40		150	°C

Diode, Revers / Diode, Reverse

Höchstzulässige Werte / Maximum Rated Values

Periodische Spitzensperrspannung Repetitive peak reverse voltage	$T_{\text{vj}} = 25^\circ\text{C}$	V_{RRM}		650		V
Dauergleichstrom Continuous DC forward current		I_{F}		50		A
Periodischer Spitzenstrom Repetitive peak forward current	$t_{\text{p}} = 1 \text{ ms}$	I_{FRM}		50		A
Grenzlastintegral I^2t - value	$V_{\text{R}} = 0 \text{ V}, t_{\text{p}} = 10 \text{ ms}, T_{\text{vj}} = 125^\circ\text{C}$ $V_{\text{R}} = 0 \text{ V}, t_{\text{p}} = 10 \text{ ms}, T_{\text{vj}} = 150^\circ\text{C}$	I^2t		330 300		A^2s A^2s

Charakteristische Werte / Characteristic Values

				min.	typ.	max.	
Durchlassspannung Forward voltage	$I_{\text{F}} = 50 \text{ A}, V_{\text{GE}} = 0 \text{ V}$ $I_{\text{F}} = 50 \text{ A}, V_{\text{GE}} = 0 \text{ V}$ $I_{\text{F}} = 50 \text{ A}, V_{\text{GE}} = 0 \text{ V}$	$T_{\text{vj}} = 25^\circ\text{C}$ $T_{\text{vj}} = 125^\circ\text{C}$ $T_{\text{vj}} = 150^\circ\text{C}$	V_{F}		1,55 1,50 1,45	1,95	V V V
Wärmewiderstand, Chip bis Gehäuse Thermal resistance, junction to case	pro Diode / per diode		R_{thJC}			1,15	K/W
Wärmewiderstand, Gehäuse bis Kühlkörper Thermal resistance, case to heatsink	pro Diode / per diode $\lambda_{\text{Paste}} = 1 \text{ W/(m}\cdot\text{K)}$ / $\lambda_{\text{grease}} = 1 \text{ W/(m}\cdot\text{K)}$		R_{thCH}		0,12		K/W
Temperatur im Schaltbetrieb Temperature under switching conditions			$T_{\text{vj op}}$	-40		150	°C

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NTC-Widerstand / NTC-Thermistor

Charakteristische Werte / Characteristic Values

			min.	typ.	max.	
Nennwiderstand Rated resistance	$T_C = 25^\circ\text{C}$	R_{25}		5,00		k Ω
Abweichung von R100 Deviation of R100	$T_C = 100^\circ\text{C}, R_{100} = 493 \Omega$	$\Delta R/R$	-5		5	%
Verlustleistung Power dissipation	$T_C = 25^\circ\text{C}$	P_{25}			20,0	mW
B-Wert B-value	$R_2 = R_{25} \exp [B_{25/50}(1/T_2 - 1/(298,15 \text{ K}))]$	$B_{25/50}$		3375		K
B-Wert B-value	$R_2 = R_{25} \exp [B_{25/80}(1/T_2 - 1/(298,15 \text{ K}))]$	$B_{25/80}$		3411		K
B-Wert B-value	$R_2 = R_{25} \exp [B_{25/100}(1/T_2 - 1/(298,15 \text{ K}))]$	$B_{25/100}$		3433		K

Angaben gemäß gültiger Application Note.
Specification according to the valid application note.

Modul / Module

Isolations-Prüfspannung Isolation test voltage	RMS, f = 50 Hz, t = 1 min.	V_{ISOL}		2,5		kV
Material Modulgrundplatte Material of module baseplate				Cu		
Innere Isolation Internal insulation	Basisisolation (Schutzklasse 1, EN61140) basic insulation (class 1, IEC 61140)			Al ₂ O ₃		
Kriechstrecke Creepage distance	Kontakt - Kühlkörper / terminal to heatsink Kontakt - Kontakt / terminal to terminal			15,0 12,5		mm
Luftstrecke Clearance	Kontakt - Kühlkörper / terminal to heatsink Kontakt - Kontakt / terminal to terminal			11,0 7,0		mm
Vergleichszahl der Kriechwegbildung Comperative tracking index		CTI		> 200		
			min.	typ.	max.	
Modulstreuintuktivität Stray inductance module		L_{sCE}		20		nH
Modulleitungswiderstand, Anschlüsse - Chip Module lead resistance, terminals - chip	$T_C = 25^\circ\text{C}$, pro Schalter / per switch	$R_{\text{CC+EE}}$		1,40		m Ω
Lagertemperatur Storage temperature		T_{stg}	-40		125	°C
Anzugsdrehmoment f. Modulmontage Mounting torque for modul mounting	Schraube M5 - Montage gem. gültiger Applikationsschrift Screw M5 - Mounting according to valid application note	M	3,00	-	6,00	Nm
Anzugsdrehmoment f. elektr. Anschlüsse Terminal connection torque	Schraube M6 - Montage gem. gültiger Applikationsschrift Screw M6 - Mounting according to valid application note	M	3,0	-	6,0	Nm
Gewicht Weight		G		400		g

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